Effect of Crystallographic Orientation on the Corrosion of Magnesium: Comparison of Film Forming and Bare Crystal Facets using Electrochemical Impedance and Raman Spectroscopy

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The corrosion rate of Mg indicates a strong crystallographic dependence in chloride-containing, alkaline environments that correlates inversely with oxide film thickness. In contrast, a different crystallographic orientation dependency is observed initially during open circuit corrosion in non-chloride containing, near neutral pH buffered, chelating environments such as Tris(hydroxymethyl)aminomethane (TRIS) and Ethylenediaminetetraacetic (EDTA) which minimize air-formed MgO oxides. The origins of the differences in the rates of the coupled corrosion processes as a function of crystallographic orientation were investigated utilizing electrochemical impedance spectroscopy (EIS) and Raman vibrational spectroscopy. High frequency constant phase elements (CPEs) were exploited to determine oxide thicknesses as a function of crystal orientation. In unbuffered NaCl, open circuit corrosion was faster on basal planes while lower corrosion rates were observed on low index, prismatic and pyramidal planes. This variation in rate with crystallographic orientation in 0.6 M NaCl was interpreted to depend on the MgO and Mg(OH)2 film thicknesses as a function of orientation. In particular, crystal planes with a lower MgO/Mg(OH)2 thickness corroded at higher rates as assessed in-situ by EIS and suggested by Raman spectroscopy. The crystallographic orientation dependence of corrosion seen initially upon exposure in the buffered neutral pH environments corresponded with crystal facet surface energy for bare Mg but this trend disappeared with exposure time and Mg(OH)2 films were then detected.

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1. INTRODUCTION

1.1. Corrosion Dependence on Crystallographic Orientation for Various Metal Systems

For many metals and alloys, the corrosion rate has been found to exhibit strong dependence on crystallographic orientation [1–5]. Assessing anisotropic corrosion properties by using single crystal samples limits the number of facets tested [3,4,6,7]. While such studies give an indication of the corrosion properties of specific orientations, limitation to a few crystal planes can confound understanding of the corrosion properties of the system as a whole [3,4,6,7]. This paucity of grain orientations at closely spaced h, k, l Miller-Bravais indices values falls short because corrosion properties can vary significantly over only a few degrees difference in crystallographic orientation [1]. Consideration of a large number of grains on polycrystalline samples on a grain by grain basis over small differences in h, k, l values provides the opportunity to uncover the true orientation dependence of dissolution and corrosion rate as a function of surface plane orientation.

Moreover, significant differences in findings as well as interpretation of crystal orientation effects on corrosion often occur [1–13]. For body-centered cubic (bcc) stainless steel in 0.6 M NaCl, the highest percentage of pitting events was observed on planes oriented ~25° away from (001) [8] while in contrast the (100) orientation was reported to have the highest corrosion rate in H2SO4 [2] and NO3− [9]. For face-centered cubic (fcc) Al in NaOH, orientations near [111] indicated the most corrosion [10–12]. The effects of crystal structure on atomic bonding between nearest neighbors, coordination, the number of dangling bonds and

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resultant surface energy, film thickness, film/substrate epitaxy [1,2,6,13] as well as the reaction thermodynamics and kinetics at the metal-oxide-solution interface during both passive and active corrosion should all be considered to better understand the influence of crystallographic orientation on corrosion [3,7]. However, a careful comparison is required on the same alloy under both film covered and bare, actively dissolving conditions because orientation effects may differ in each case.

1.2. Crystallographic Orientation Dependence on Corrosion for Mg and Mg Alloys

A systematic sampling of orientations in Mg alloys is lacking or has been complicated due to the substantial crystallographic texture of Mg alloy sheet or plate often formed upon mechanical processing [14–17]. For these reasons, as well as the historical inability to accurately assess corrosion and dissolution rates in Mg system by electrochemical methods [18–20], conflicting results have been reported regarding the orientation dependence of Mg corrosion [21,22]. Corrosion was observed on planes that were oriented with a normal near the (0001) direction with respect to the sample surface in NaCl environments containing dichromate ions [23]; One study examined Mg in 0.1 N HCl and studied grains after EBSD and AFM where the (0001) planes were argued to be most corrosion resistant [22]. The basis for this claim is unclear. Many grains with high orientations exhibited striations after corrosion that were argued to be made up of (202), (0001), (1120) and (01T0) planes. Some of these facets are likely slowly dissolved planes seen after fast dissolving planes grow themselves out of existence as shown elsewhere [1]. When tested in NaCl, the rolling plane (heavily textured to favor the basal plane) of wrought AZ31 exhibited greater H2 evolution than cross-sections suggesting an effect of texture on corrosion rate but the difference was later attributed to the prevalence of particles such as Al6Mn5, and not crystal orientation effects [21,24]. The Mg (0001) surface exhibited pitting corrosion susceptibility at the open circuit potential (OCP) while the (10T0), and (1120) surfaces were passive at open circuit and pitting only initiated at potentials slightly anodic to their open circuit potentials in a similar environment [25]. Validation of the corrosion rate of various crystallographic orientations in Mg based materials has also involved alloys [26,27]. Mg-Al alloys (such as AZ31) corroded at a lower rate on the closely packed basal plane [26], although this was also complicated by the presence of secondary phases. In another study, SKP, SVET, EIS and E-log(j) were focused on two Mg grains in NaCl and saturated Mg (OH)2 solution [21]. One had an orientation between (0001) and (10T0) and the other was close to (1120) on a grain facet which also contained twins. The grain near (0001) had the greatest corrosion rate by EIS and E-log(j) and the oxide film was thinner, which is similarly shown by the work in this study. The corrosion dependency might have been governed by film thickness as the (0001) film was thinner. This was not reported but evident from the work. The authors were instead concerned that films “concealed” the effects of orientation, not recognizing that it might be a controlling factor [21]. No other orientations were attempted. Therefore, there is limited comprehensive comparison between the corrosion rate and overall effects of dissolution on the resultant morphology on many individual grains as a function of crystallographic orientation not clouded by these factors.

The work herein comprises of a full analysis of the EIS frequency response on polycrystalline materials as well as an in depth analysis on the corrosion morphology via SEM and Electron Backscatter Diffraction (EBSD). Rate data is correlated with Raman spectroscopy in both attempts to produce film free and film covered cases. In work to date on the crystallographic orientation on Mg, while there has been some work on polycrystalline pure Mg samples [21,22], the work has only evaluated a few orientations and has not shown a wide breath in the evaluation techniques. In particular EBSD correlated with surface topography measurements, such as profiometry techniques now enables understanding of the dissolution behavior of a large number of crystal planes [1] as has been performed here. In this study, these prior difficulties have been overcome by EBSD analysis of many grains. Profiometry and electrochemical impedance spectroscopy (EIS) were both conducted on individual, isolated grains to reveal the orientation dependence of corrosion under open circuit conditions.

1.3. Effect of Surface Energy on Crystallographic Dissolution

Existing literature on Mg suggests that surface energy varies with crystal orientation. The surface energy for Mg (0001), (10T0) and (10T2) surfaces are 0.9, 1.2 and 1.4 J/m2, respectively, as calculated with empirical electron theory [6,28]. This implies that exposed faces close to the (0001) plane should have a lower thermodynamic driving force and might corrode slower than those planes which are oriented slightly different than the (0001) plane from a surface energy minimization perspective [23]. Previous work on bare fcc Fe–Pd shows that the highest dissolution occurred at planes oriented approximately 45° from the (100) orientation which correlated to the highest determined surface energy [1]. However, Mg is a system which corrodes in [Cl ] solutions far from equilibrium [1].

1.4. Nature and Crystallographic Aspects of the Native Oxide Film on Mg

For Mg, the oxide film is affected by factors such as solution pH, where a more protective film is typically formed in alkaline solutions [29–32]. Several techniques have been used to analyze the nature of this film. The surface film formed on Mg is duplex in nature, consisting of a thin, nano-crystalline MgO inner layer and a Mg(OH)2 platelet layer [33–35]. X-ray photoelectron spectroscopy (XPS) [36–38] and focused ion beam (FIB) [29,35,39] studies on the surface of Mg have shown that the surface film consists of both MgO and Mg(OH)2 [40]. The initial, crystalline MgO layer is formed during exposure to air. Hydration of the bulk inner MgO layer occurs and the layer thickens to form the outer Mg(OH)2 corrosion product [29,35]. The thickness of the oxide layer on Mg has been calculated through XPS and FIB cross-section [29,35,39]. While this thickness is extremely dependent on exposure time and environment, the outer, Mg(OH)2 layer is typically on the order of ~500 nm in thickness and flake-like while the inner MgO layer is only on the order of ~50–90 nm thick [29,35,39]. MgO films on the basal (0001) surface are thinner than those on either (01T0) and (1120) in dilute sodium sulphate solutions [41]. This relationship has been similarly reported for polycrystalline hexagonal close packed (hcp) Ti using EBSD measurements [42]. While the (0001) and (01T0) planes consist of equiaxed crystals of MgO, the (1120) surface forms MgO with oriented flakes perpendicular to the metal/oxide interface [29,35].

1.5. Opportunity to Ascertain Crystallographic Dependence of Simultaneous Corrosion and Oxide Formation with Impedance Spectroscopy

The use of electrochemical impedance spectroscopy (EIS) gives a reliable and repeatable estimation of the instantaneous corrosion rate on Mg and its alloys [18–20]. The components of the equivalent circuit have been shown to correspond to the Mg
Table 1 Composition of 99.9% Mg Rod (Alfa Aesar). All compositions reported in wt. %, with the actual compositions provided by QUANT (Quality Analysis and Testing Corporation).

<table>
<thead>
<tr>
<th></th>
<th>Al</th>
<th>Mn</th>
<th>Zn</th>
<th>Si</th>
<th>Cu</th>
<th>Ni</th>
<th>Fe</th>
<th>Mg</th>
</tr>
</thead>
<tbody>
<tr>
<td>Mg Rod</td>
<td>0.01</td>
<td>0.01</td>
<td>0.01</td>
<td>0.02</td>
<td>0.05</td>
<td>0.001</td>
<td>0.006</td>
<td>Bal.</td>
</tr>
</tbody>
</table>

sample surface and described in terms of their physical meaning [43]. Therefore, oxide film thickness may be determined under in-situ conditions. The goal of this research was to utilize EIS to understand the effects of crystallography on oxide thickness and corrosion rate for oxide ‘free’ and oxide covered crystal surfaces.

The EIS determined oxide thickness has been achieved for other material systems, such as Ni-Cr-Mo [44, 45], Al [45, 46] and the hcp Zr [5] but further analysis in the Mg system is needed. The circuit diagram for accurate EIS determination in Mg has been recently suggested in other work (Fig. 2) [43]. The use of two capacitive circuit elements is necessary in order to model the full frequency response of the Mg to the electrolyte [18, 43]. The high frequency capacitor, \( C_1 \), represents the passive oxide and possibly Mg(OH)\(_2\) films while the low frequency capacitor, \( C_2 \), represents the double-layer capacitance or pseudo-capacitance. These two capacitances can be simultaneously determined in the case where the capacitances differ in magnitude [43]. Good correlation has been shown between the percent area of corroded surface and the capacitive elements [43, 47], showing that the thickness of this oxide with time can be determined by these capacitive values.

1.6. Objective

The objective of this study is to understand origins of the crystallographic dependence of the corrosion and dissolution rate in a polycrystalline Mg sample under film and film-free conditions. The work herein is the first of its kind to perform EIS on a large number of single grains in a polycrystalline material system (as compared to single crystals) in order to assess both oxide thickness and to determine the open circuit corrosion rate as a systematic function of orientation.

2. EXPERIMENTAL PROCEDURES

2.1. Materials

Extruded commercially pure Mg rod was provided by Alfa Aesar. The sample was re-melted and re-solidified to randomize the texture or minimize the as-received extruded texture. All compositions are reported in wt. %, provided by QUANT (Quality Analysis and Testing Corporation) via Inductively Coupled Plasma optical Emission Spectroscopy (ICP-OES) analysis (Table 1).

2.2. Metallurgical Sample Characterization

2.2.1. Sample Heat Treatment for Large Grain Growth

All polycrystalline samples have been heat treated to alleviate deformation twins formed during previous processing. Commercially pure Mg samples were heat treated at 575 °C for 5 h to achieve a grain size of approximately 1.5 mm in diameter. This enabled grains to be easily located by SEM, EIS and optical microscopy before and after corrosion.

2.2.2. Electron Backscatter Diffraction

Optical and electron microscopy as well as scanning electron microscopy (SEM) were performed using a Hirox optical and FEI Quanta 650 microscope, respectively. Samples were polished through colloidal silica, iron flat milled and etched with a Picric acid etch (3 g picric acid, 30 mL acetic acid, 100 mL ethanol and 15 mL distilled water) immediately before being placed in the SEM. Etching removed the MgO oxide which may have formed, even after ion polishing, to enable improved EBSD imaging. Samples were rapidly polished (\(<1 \mu m\)) to maintain some of the etched microstructure for grain identification after EBSD but to remove any carbon contamination from the SEM before corrosion analysis. EBSD was performed at low magnification to image a large number of grains at once and analyzed using Aztec™ [48]. Approximately 200 grains were analyzed over multiple EBSD micrographs.

Fig. 1. Schematic representation of (hkil) positions defined by the angular distance, \( \beta_h \), from the 3 common low index hexagonal planes: \{0001\}, \{01\bar{1}0\} and \{\bar{T}2\bar{T}0\}.

Fig. 2. (a) Electrical equivalent circuit diagram used to model pseudo-inductive electrochemical impedance response and to determine \( R_p \) on corroding Mg in 0.6 M NaCl solution and (b) the equivalent circuit diagram used to determine the oxide thickness and \( R_p \) in 0.1 M TRIS and EDTA. Constant phase elements were modeled using ideal capacitors when \( \alpha \) was within 10% of 1.
Fig. 3. Typical Kramers-Kronig transforms of the real and imaginary components of the impedance of high purity Mg after 24 h immersion in (a) 0.6 M NaCl, (b) 0.1 M EDTA and (c) 0.1 M TRIS.
Table 2

Typical fitting results of electrochemical impedance measurements made on commercially pure Mg, in 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA solution at open circuit after 24 h of immersion, as per the equivalent circuits seen in Fig. 2.

<table>
<thead>
<tr>
<th></th>
<th>0.6 M NaCl</th>
<th>0.1 M TRIS</th>
<th>0.1 M EDTA</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_e$ (Ω cm$^2$)</td>
<td>23</td>
<td>37</td>
<td>40</td>
</tr>
<tr>
<td>$C_1$ (μF cm$^{-2}$)</td>
<td>$2.0 \times 10^{-6}$</td>
<td>$1.5 \times 10^{-5}$</td>
<td>$1.0 \times 10^{-5}$</td>
</tr>
<tr>
<td>$R_1$ (Ω cm$^2$)</td>
<td>720</td>
<td>140</td>
<td>190</td>
</tr>
<tr>
<td>$C_2$ (μF cm$^{-2}$)</td>
<td>$2.0 \times 10^{-5}$</td>
<td>$2.0 \times 10^{-5}$</td>
<td>$8.0 \times 10^{-5}$</td>
</tr>
<tr>
<td>$R_2$ (Ω cm$^2$)</td>
<td>170</td>
<td>220</td>
<td>130</td>
</tr>
<tr>
<td>$L$ (Ω cm$^2$)</td>
<td>400</td>
<td>–</td>
<td>–</td>
</tr>
<tr>
<td>$R_3$ (Ω cm$^2$)</td>
<td>920</td>
<td>–</td>
<td>–</td>
</tr>
</tbody>
</table>

2.2.3. Corrosion Morphology and Oxide Thickness in Various Electrolyte Environments

Secondary electron SEM micrographs were taken of each sample before and after immersion in unbuffered 0.6 M NaCl, 0.1 M Tris(hydroxymethyl)aminomethane (TRIS) and 0.1 M Ethylenediaminetetraacetic acid (EDTA) for 12 h at OCP. The starting pH for each of these environments was 5.1, 7 and 8, respectively. TRIS and EDTA are both chelating, buffering agents, which chemically dissolve oxide films and, therefore, enable Mg corrosion studies without a thick MgO or Mg(OH)$_2$ oxide layer [49]. All samples were cleaned after corrosion testing with CrO$_3$ to remove any corrosion products and examine the corrosion morphology [50]. 3D images were also obtained using a Hirox optical microscope to determine the depth of corrosion. The area-fraction of the sample surface which was corroded in the form of dark areas, if observed, was determined using the software package, ImageJ$^\text{TM}$ [51]. The corroded area-fraction of the sample surface was determined using the software package Mountains$^\text{®}$ [52].

2.2.4. Surface and Corrosion Film Characterization

Raman spectroscopy was performed utilizing a Renishaw InVia Raman Microscope after exposure to 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA after immersion in these various environments for 24 h at OCP. Samples were analyzed utilizing a 514 nm laser at 50% power under at 50 x objective lens with 3000 l/mm grating. Raman analysis was performed on approximately three spots on the sample surface and a typical Raman spectrum is reported.

2.2.5. Texture and Orientation Determination of Each Grain

The Euler angle $\Phi$ from the Bunge convention was used to report the (hkil) pole normal to the orientation of a surface exposed crystal facet in a grain [53]. The Euler angles of each plane normal, with respect to the $\{001\}$ plane, were reported, as exported from the Aztec [48] software, and the (hkil) were

Fig. 4. (left) Nyquist plots and (right) Bode magnitude and phase plot for pure polycrystalline Mg. Data shown along with respective fits following 24 h immersion in 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA at open circuit. Parameters reported in Table 2.

Fig. 5. Secondary electron micrographs of (a) commercially pure Mg before exposure, (b) commercially pure Mg EBSD before exposure, (c) commercially pure Mg after exposure in 0.1 M TRIS, (d) pure Mg before exposure, (e) commercially pure Mg EBSD before exposure, (f) commercially pure Mg after exposure in 0.1 M EDTA.
determined from Eq. (1) [54].

\[
\begin{bmatrix}
 h \\
 k \\
 i \\
 l
\end{bmatrix} = \begin{bmatrix}
 \frac{\sqrt{3}}{2} & -1 & 0 \\
 0 & 1 & 0 \\
 -\frac{\sqrt{3}}{2} & -1 & 0 \\
 0 & 0 & \frac{c}{a}
\end{bmatrix} \begin{bmatrix}
 \sin \beta \sin \phi \\
 \cos \beta \sin \phi \\
 \cos \phi
\end{bmatrix}
\]

(1)

Where \(h, k, i \) and \(l\) are the Miller-Bravais indices and \(c/a\) is approximately 1.624 for Mg, where \(c = 5.21\ \text{Å}\) and \(a = 3.21\ \text{Å}\).

To describe the Miller-Bravais index of each plane on an exposed grain facet, \(\{hkil\}\), the variables, described in Fig. 1, were used to describe a given \(\{hkil\}\) on an inverse pole figure (IPF). The \(\{hkil\}\) was defined in terms of the interplanar angles, \(\beta\), the angle measured from a primary low index hexagonal plane normal to the \(\{hkil\}\) of interest and the \(\alpha\), the angle between \(\beta\) and either great circles from the \(\{0001\}\) to \(\{01\overline{1}0\}\) or from \(\{0001\}\) to \(\{\overline{1}2\overline{1}0\}\). The interplanar angles between any two planes \(\{h_1k_1l_1\}\) and \(\{h_2k_2l_2\}\) in the hexagonal system were determined from Eq. (2) [55].

\[
\cos \phi = \frac{h_1h_2 + k_1k_2 + \frac{1}{2}(h_1k_2 + h_2k_1) + \frac{1}{2}(h_1^2 l_2 + h_2^2 l_1)}{\sqrt{(h_1^2 + k_1^2 + h_1k_1 + \frac{1}{2}h_1^2 l_2)(h_2^2 + k_2^2 + h_2k_2 + \frac{1}{2}h_2^2 l_1)}}
\]

2.3. Corrosion Behavior Determination by EIS

The corrosion behavior of single grain facets of commercially pure Mg was monitored with EIS over a 24 h immersion period in 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA at OCP. The isolation of individual grain facets was accomplished using electroplaters tape with a 1.23 mm² area hole to expose each grain. EIS data were acquired from 100 kHz to 0.001 Hz with 6 points per decade and an
Table 3
Relative Raman peak intensity ratios of MgOH₂ as determined via Raman Spectroscopy in 0.1 M NaCl and 0.1 M EDTA.

<table>
<thead>
<tr>
<th>Concentration</th>
<th>442 cm⁻¹</th>
<th>278 cm⁻¹</th>
</tr>
</thead>
<tbody>
<tr>
<td>[MgOH₂] in NaCl</td>
<td>1</td>
<td>1</td>
</tr>
<tr>
<td>[MgOH₂] in TRIS</td>
<td>0.3</td>
<td>0.5</td>
</tr>
<tr>
<td>[MgOH₂] in EDTA</td>
<td>0.1</td>
<td>0.4</td>
</tr>
</tbody>
</table>

AC amplitude of ±20 mV. EIS scans were analyzed and fit using the software program ZView [56] to fit an equivalent circuit, seen in Fig. 2, and were fit to a low frequency limit of at least 0.01 Hz for 0.1 M TRIS and 0.1 M EDTA and to 0.001 Hz for 0.6 M NaCl.

Fig. 2(a) consists of a set of series and parallel resistors and capacitors [i.e., \( R_1/(R_2+R_3) \)] (where “/” indicates series and “+” indicates parallel) and a series resistor inductor combination (i.e., \( R_3/L \)). Fig. 2(b) has excluded this last series resistor inductor combination as the final inductive loop does not appear in the TRIS and EDTA environments. In this circuit, \( R_0 \) in the circuit represents the solution resistance and is specific to the exposure environment. \( R_1, R_2 \) and \( R_3 \) represent the various resistances due to oxides and hydroxides as well as anodic and cathodic reactions on the Mg surface or oxide/film interface which are affected by the local environment [18,19,43]. The capacitors (or in some cases CPE’s), \( C_1 \) represents the capacitance associated with the oxide/hydroxide layers. \( C_1 \) is similar to the parallel combination of \( C_{ox} \) and \( C_{af} \) for oxide/hydroxide and the air oxide used elsewhere [43]. \( C_2 \) may be a double layer capacitance, adsorption pseudo-capacitance and may differ based on environment. \( R_1+R_2 \) are related to the oxide resistance and interface charge transfer resistance, respectively, (termed the \( R_{ct} \) in this and other work [19,20,43,57]). Last, the inductor \( L \) represents a reaction rate that changes with the reaction mediating coverage of intermediates.

The inclusion of the full inductive frequency response of Mg enables for a more accurate determination of the anodic charge produced for Mg alloys by the inclusion of the full polarization resistance, \( R_p \), established at low frequencies [18,19]. The determination of \( R_p \) was calculated using the following equation as reported elsewhere [18,19,43] for Fig. 2(a) and (b) respectively.

\[
\frac{1}{R_p} = \frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3}
\]

\[
R_p = R_1 + R_2
\]

Where \( R_1, R_2 \) and \( R_3 \) represent the resistors within the circuit model and have been defined above. The anodic charge produced for each grain was determined through integration of \( 1/R_q(t) \) with respect to time using the Stern-Geary equation [58] as detailed in Eq. (5).

\[
Q_{\text{EIS}} = \int_{j_{\text{corr}}}^{t_{\text{end}}} \frac{\beta_s \beta_c}{2.303 R_0(t) (\beta_s + \beta_c)} dt
\]

It has been shown previously, that the Mg interface as interrogated by AC methods in chloride-containing environment can be considered reasonably stationary through the direct integration of the Kramers-Kronig (K-K) transformations of the real and imaginary components [59,60]. There is good correlation and low residual noise (\( < < 1 \% \) of calculated) as low as 0.001 Hz for 0.6 M NaCl (Fig. 3(a)). Recall that the inductive loop, which is typically observed on Mg in the chloride-containing environments at low frequencies is observed in unbuffered 0.6 M NaCl [19]. However, in the TRIS and EDTA environments, good correlation could only be achieved to 0.01 Hz (Fig. 3(b and c)). There is no valid inductive loop in the scattered data seen at low frequencies. This agrees with previous work which has found that this solution lacked a well-defined inductive loop as it is typically seen in the [Cl⁻] environments [19].

The corrosion penetration depth was calculated from Faraday’s law:

\[
x = \frac{Q(E.W.)}{F \rho}
\]

Where E.W. is the equivalent weight of commercially pure Mg, taken as 12.16 g/eq, \( F \) is Faraday’s constant (96,485 C/eq), and \( \rho \) is the density of Mg. This corrosion depth is important for single grain EIS analysis, particularly for highly reactive Mg samples. If the material corrodes deeper than the depth of a grain (relative to \( x = 0 \mu m \) at the sample surface) then the crystallographic dependence determined through single grain EIS is lost. Therefore, an absolute upper bound in corrosion was taken as the grain size/2. However, it is recognized that corrosion beyond the first 100 atom layers may result in a corroded surface different from the crystallographic orientation of the face of the grain first exposed [1].

2.4. Film Thickness Determination by EIS

The film thickness on individual grains was determined by EIS over a 24 h immersion period in 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA using the software program ZView [56] to fix experimental data to the equivalent circuit Fig. 2(a) for 0.6 M NaCl or Fig. 2(b) for 0.1 M TRIS and EDTA solutions due to the variation in physical presence or absence of films. The equivalent circuits were comprised of constant phase elements (CPEs). A CPE impedance, \( Z_{\text{CPE}} \), can be expressed in terms of the model parameters \( \alpha \) (a time-constant) and \( Y_0 \) (CPE parameter) as shown in Eq. (7) [61] were the CPE parameter was used for \( C_1 \) for determining the inner oxide thickness.

\[
Z_{\text{CPE}} = \frac{1}{(j\omega)^\alpha Y_0}
\]

Where \( j \) is an imaginary number and \( \omega \) is the AC frequency response. The oxide film can be modeled as a capacitor [43]. For an ideal capacitor, \( \alpha = 1 \), where \( Y_0 = C \), however, \( \alpha \) varied in Fig. 2(a and b) with time. In the case of an ideal capacitor, the effective dielectric capacitance, \( C_{\text{eff}} \), of the film can be expressed by Eq. (8).

\[
C_{\text{eff}} = \frac{\varepsilon_{\text{sample}} A}{\varepsilon_{\text{ox}}}
\]

Where \( \varepsilon \) is the dielectric constant for MgO taken to be 9.8, \( \varepsilon_{\text{ox}} \) is the permittivity of vacuum (8.84x10⁻¹⁴ F/cm) [62], \( A \) is the sample exposure area and \( \varepsilon_{\text{ox}} \) is the oxide thickness. In the case of a non-ideal capacitor (such as in Fig. 2(a and b)), the effective capacitance, \( C_{\text{eff}} \), can be obtained from a constant phase element [63].

\[
C_{\text{eff}} = \frac{Y_0}{(2\pi\omega)^\alpha \varepsilon_{\text{ox}}}
\]

Where \( \alpha \) is the frequency where \( Z_{\text{CPE}} \) reaches a maximum [63]. From determination of \( C_{\text{eff}} \) as necessary, Eq. (8) can be used to determine the oxide thickness from \( C_1 \). For this analysis, \( Y_0 \) and \( \alpha \) for \( C_1 \) and \( C_2 \) respectively, were both determined via fitting of the equivalent circuits (Fig. 2).

\footnote{It is recognized that the fast dissolving planes may largely disappear at smaller depths than the grain diameter to reveal slow dissolving facets as seen in Ref. [1]. However, EBSD is a bulk technique sampling electrons from depths over which dissolution occurred.}

\footnote{Data below the K-K transform limit determining data that was not valid was excluded in this analysis.}
Fig. 8. (a) EBSD map of polycrystalline commercially pure Mg and (b) corresponding secondary SEM micrograph showing the marked, specified grains after exposure after 3 h immersion at OCP in 0.6 M NaCl and cleaned with CrO₃ to remove any oxides. The color refers to the IPF in Fig. 1.

Fig. 9. (a) EBSD map showing strongly oriented basal grain and (b) secondary SEM micrograph showing preferential dissolution of the basal oriented grain after exposure after 3 h immersion at OCP in 0.6 M NaCl and cleaned with CrO₃ to remove any oxides. The color refers to the IPF in Fig. 1. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

Fig. 10. (a) Schematic of corrosion penetration depth assuming uniform corrosion for isolated grains as calculated from EIS determined $j_{corr}$ as a function of the $\beta_{\{0001\}}$ angle in (b) 0.6 M NaCl, (c) 0.1 M TRIS and (d) 0.1 M EDTA at OCP over a 24 h immersion. The dashed line indicates the half grain diameter.
Higher corrosion rates may also be indicative of the lack of changes in the local surface environment in these buffered solutions, specifically usual elevation of pH towards the Mg\(^{2+}/\text{Mg(OH)}_2\) equilibrium [66]. The pH for the chloride containing environments before exposure was typically around 5.3 before becoming more alkaline with the generation of OH\(^-\) ~10, immediately after corrosion of Mg in the unbuffered solution. At pH ~10, MgO and Mg(OH)_2 are thermodynamically stable [66,67]. However, the bulk pH of the buffer solutions remained near 7 and 8 which would not thermodynamically support the formation of MgO or Mg(OH)_2. Mg exposed to 0.1 M TRIS and 0.1 M EDTA showed max 1/R_p or j_corr at intermediate β-angles suggesting a crystallographic orientation dependence that will be discussed below (Fig. 5a–f). However, samples exposed to 0.6 M NaCl (Fig. 6) showed various corrosion morphologies as a function of the initial crystallographic orientation after the samples were cleaned with CrO_3. The low index plane {01T0} indicated a wide “filiform-like” corrosion morphology while other, higher index grains, displayed terraces instead of this filiform type morphology [11].

The molecular identity of the oxide films, formed in the 0.6 M NaCl, 0.1 M TRIS and 0.1 M EDTA exposure environments, were confirmed through Raman spectroscopy (Fig. 7). Fitting of the Raman shift to the characteristic Mg(OH)_2 peaks indicated a strong presence of the Mg(OH)_2 film in the chloride containing 0.6 M NaCl solution. These peaks had a lower intensity in the EDTA and TRIS...
solutions which suggests that only a small amount of Mg(OH)$_2$ was present which was likely a remnant of the air formed film or due to metastable film formation. It is noted that analysis of the Raman signal should be treated with caution. In particular, the assessment here is not to give a quantitative evaluation of oxide thickness with Raman Spectroscopy. Instead, this technique simply gives an assessment of the presence of this hydroxide. MgO (or the MgO stretch) was not detected through Raman Spectroscopy, even after thermal oxidation of the material suggesting significant hydroxylation of oxides. However, an assessment of the relative peak intensity ratios can give some understanding into the amount of oxide present on the sample surface as a function of exposure environment following previous work on Pb oxides using a similar method [68]. The relative peak intensity ratios of the oxides for two characteristic Raman peaks are reported in Table 3 where the peak intensity was determined from the normalized peak intensities in Fig. 7. This analysis indicates more Mg(OH)$_2$ in the NaCl environment than either TRIS or EDTA.

3.3. Crystallographic Dependent Corrosion in Polycrystalline Mg

Polycrystalline samples were exposed to 0.6 M NaCl after EBSD characterization. The orientation of each grain was determined, as shown in Figs. 8 (a) and 9 (a). The colors on the EBSD map correspond to those shown in Fig. 1(b). After a 12 h immersion at open circuit in 0.6 M NaCl, some grains preferentially corroded and developed characteristic dark areas [20,43,49] while other grains remained intact. In Fig. 8(b), grain 18 was substantially corroded by the filiform morphology [69–72]. This grain had an orientation approximately 20° from the {0 0 0 1} basal plane. However, grains 21 and 19, near {1 0 0} orientations, had not corroded. Fig. 9 displays a grain with a strong basal orientation (red grain 1). The near basal plane (labeled as 1) corroded preferentially to those of a non-basal orientation. The corrosion depth (Eq. (6)) in 0.6 M NaCl is approximately 57 μm on the basal plane after 24 h while this depth is 225 μm and 450 μm for 0.1 M TRIS and 0.1 M EDTA, respectively (Fig. 10(a–d)). The relationship between the corrosion depth is roughly linear with time for each specified [h k l] indicating an approximately constant corrosion rate. Also, the trend shows a lower corrosion propagation depth at each time with increasing β(0101) from the basal plane that is maintained over all exposure times. Therefore, the trend with initial surface crystallographic orientation is preserved through the full exposure time for each environment.

Fig. 11(a) shows the percent “dark” surface area [65,73] for different orientations after immersion in 0.6 M NaCl for 24 h at OCP. This percent has been calculated based on the dark area relative to the surface area of the grain. As the material dissolves, the sample surface becomes dark [73] and this dark region typically contains enriched transition elements [74,75] and for AZ31B possibly by Al chemical deposition [47]. The exchange current density for the hydrogen evolution reaction (HER), the dominant cathodic reaction on Mg, increases with time due to this enhanced cathodic activity [64,76,77]. The dissolution behavior can also be plotted as the volume of material dissolved (Fig. 11(b)). The dissolution, expressed as volume, is highest on {0001} oriented grain facets. More specifically, grains oriented within ~30° of the basal plane
had the highest dissolution while those oriented near the \{01\overline{1}0\} and \{\overline{1}2\overline{1}0\} planes had the least dissolution.

3.4. Crystallographic Dependence on the Instantaneous Corrosion Rate on Isolated Mg Grains

For commercially pure Mg, the EIS spectra at OCP in 0.6 M NaCl had two capacitive loops and an inductive loop [37,78–85] as determined from the fits in Fig. 12. Using the equivalent circuit shown in Fig. 2(a), a reasonable fit was achieved with \( R_p = 0.95 \) for the CPE. This \( \alpha < 1 \) is typical for the case of surface heterogeneity [86] and would be particularly true for the highly reactive Mg system. Concerning \( R_p \) as a function of \( \beta_{\{0001\}} \) angle, in Fig. 12, \( R_p \) increases with increasing \( \beta_{\{0001\}} \), meaning that the \( j_{\text{corr}} \) decreased with increasing \( \beta_{\{0001\}} \) (away from the basal crystal surface) which is quite consistent with the corrosion morphology observed in Figs. 8 and 9. It was shown that the basal plane had the highest anodic charge produced the low index planes had the lowest anodic charge produced in the unbuffered NaCl solution. This is consistent with % dark area and volume lost (Fig. 11) in the NaCl solution.

EIS spectra for non-chloride containing TRIS and EDTA solution were also collected for specific grain orientations at various \( \beta_{\{0001\}} \) angles (Figs. 13 and 14). These solutions lack a well-defined inductive loop that is typically seen in the [Cl\(^-\)] environments and therefore \( 1/R_p \) was fit to the equivalent circuit (Fig. 2(b)). There is a slight variation in these environments with this trend with time. In TRIS, at 0 h there is a small peak in the anodic charge density produced over the range \( \beta_{\{0001\}} = 20^\circ - 60^\circ \) (potentially due to a surface energy effect to be discussed below) (Fig. 13). However, this trend disappears after 3 h, with the \( 1/R_p \) increasing with increasing \( \beta_{\{0001\}} \). This same trend was also determined in the non-chloride containing EDTA solution (Fig. 14).

For each of these environments, the corrosion current density was integrated over the full 24 h immersion for each of these specified crystallographic orientations (Fig. 15). It is shown that, in the 0.6 M NaCl environment the anodic charge density from open circuit corrosion (Eq. (5)) and corrosion depth (as determined via Eq. (6)) decrease with increasing \( \beta_{\{0001\}} \) angle. However, in the TRIS and EDTA environments, there is also a small peak in anodic charge after open circuit corrosion and depth around \( \beta_{\{0001\}} = 60^\circ \). This correlates to the plane with the highest surface energy [6,28].

3.5. Effect of Oxide Thickness on the Crystallographic Orientation Dependent Corrosion of Mg

The model-determined oxide thickness (determined through Eq. (8)) was highly dependent on the capacitive response in the Mg system [43]. \( C_1 \) typically had a value of \( \sim 10^{-10} \) F/cm\(^2\) in NaCl while \( C_2 \) had a value of approximately \( \sim 10^{-5} \) F/cm\(^2\) or larger depending on active dark area [43]. However, in TRIS and EDTA \( C_1 \) was \( \sim 10^{-5} \) F/cm\(^2\) while \( C_2 \) ranged from \( 10^{-4} \) to \( 10^{-3} \) F/cm\(^2\). From a sensitivity analysis using circuit model Fig. 2(a), replacing the CPE with a capacitor, \( C_1 \) can be distinguished from \( C_2 \) when \( C_2 \neq C_1 \).
However, when \( C_1 \) was similar to \( C_2 \), one 1st quadrant depressed semi-circle appears as the time constants for \( R_1C_1 \) and \( R_2C_2 \) are too similar to produce two distinct depressed semicircles (Fig. 16(a and b)). EIS fitting in 0.6 M NaCl (Fig. 12), \( C_1 \) and \( C_2 \) might be similar depending on dark area while, in Figs. 13 and 14 (i.e. in TRIS and EDTA) the values differ. The oxide thickness was determined in the circuit model of Fig. 2(a), initially assuming a CPE. \( Y_0 \) was close to an ideal capacitor, with \( \alpha \approx 0.95 \) for most fits (Eqs. (7)-(9)). In summary, \( \Delta_x \), for the compact MgO layer, as determined through Eq. (8), was determined from \( C_1 \) (using a CPE).

The EIS determined oxide thickness is plotted in Fig. 17 for 0.6 M NaCl. The change in this thickness was plotted as a function of the \( \beta_{(001)} \) value or the distance from the basal plane Fig. 17(a). It was observed that the planes furthest from the basal plane had the thickest determined oxide (≈40 nm) while those planes close to the basal plane had a thinner oxide thickness (≈5 nm) which is consistent with the results reported elsewhere [29,35,37-39]. The total charge was inversely proportional to this thickness (Fig. 15).

The oxide thickness as a function of \( \beta \) angle was also determined for the non-chloride containing TRIS and EDTA environments (Fig. 17(b and c)). The oxide thickness was determined using the equivalent circuit in Fig. 2(b) and EIS data which is K-K valid to 0.01 Hz (Fig. 3). The oxide thickness was extremely small, if physically present and if realistically appraised by the approach here on the basal planes (≈0 nm) and slightly higher on the pyramidal and prismatic planes (≈1 nm). This EIS calculated oxide thickness was clearly much smaller than in the 0.6 M NaCl environment. This also agreed with the Raman which strongly suggests that either the high corrosion rate of Mg eventually saturates the buffer capacity of TRIS and EDTA or a Mg (OH)\(_2\) remnant of the air oxide exists (Fig. 7). Moreover, the variation in the \( \Delta_x \) with the calculated oxide thickness was much smaller for all crystallographic orientations in the EDTA and TRIS environments.

4. DISCUSSION

4.1. Variation in the Oxide Dissolution and Precipitation with Exposure Environment

Fig. 18(a) shows a schematic of the oxide growth on Mg in 0.6 M NaCl [39], consisting of a duplex MgO/Mg(OH)\(_2\) oxide. The thick plate-like Mg(OH)\(_2\) layer (approximately 500 nm) and is formed after exposure to H\(_2\)O [29,35] due to the hydration of the inner MgO layer and formation of Mg(OH)\(_2\) onto the sample surface [35,39,71]. The initial MgO layer nucleates on the Mg surface and is determined to be on the order or 50 nm [29,35].

The phenomenon is different in the buffered 0.1 M TRIS and 0.1 M EDTA solutions (Fig. 18(b)). Once the sample is exposed to this solution, the air-formed MgO oxide is likely dissolved for the most part by the TRIS/EDTA solution. The remaining air-formed MgO is converted to Mg(OH)\(_2\) at the sample surface and buffer capacity is exceeded, therefore a small Mg(OH)\(_2\) signal was detected by Raman Spectroscopy (Fig. 7). In the chloride environments, the typical pH after exposure is on the order of ≈10 due to the alkalization of the bulk NaCl solution to pH values in the stable region for Mg(OH)\(_2\) according to the Mg Pourbaix diagram [87]. However, both TRIS and EDTA are buffer solutions with stable pH values of 7 and 8, respectively, which would lead to less oxide

\[\text{Fig. 17. Oxide thickness and EIS determined } \Delta_x \text{ as a function of } \beta_{(001)} \text{ angle in (a) 0.6 M NaCl, (b) 0.1 M TRIS and (c) 0.1 M EDTA at OCP over a 24 h immersion as determined through an equivalent circuit shown in Fig. 2 composed of CPEs.}\]
formation according to the Mg Pourbaix diagram even after Mg$^{2+}$ production \[87\].

There was a notable difference in the thickness of this oxide as a function of both crystallographic orientation and test solution with the thinnest oxide on the basal plane and the thickest oxide on the low index orientations for each environment (Fig. \[17\](a-c)). The thickness of this oxide is inversely proportional to the corrosion rate (as denoted $j_{\text{corr}}$). From the EIS determined $j_{\text{corr}}$, the oxide thickness was on the order of 5 nm–50 nm in 0.6 M NaCl and \(<\)1 nm to 1 nm in 0.1 M TRIS and 0.1 M EDTA. MgO forms a fcc crystal structure with the Fm3m structure that in equilibrium has an epitaxial relationship with hcp Mg \[88\]. The oxide thickness on a different hcp material, Zr, was also determined through EIS \[5,89\]. The basal plane had a slower oxidation rate compared to the prismatic planes \[5,89\]. This variation in oxide growth kinetics was argued to be due to the variation in the oxygen diffusion kinetics through the high packed basal plane and the lower packed prismatic plane \[5,89\] which can lead to lower rates of passivation.

4.2. Corrosion Rates on Oxide Covered Mg Surfaces

In the chloride, film-forming environment, there was a large variation in the corrosion rates, morphology and the oxide film thickness with crystallographic orientation (Fig. \[6\]). The presence or absence of this oxide has been shown to alter the corrosion kinetics on Mg \[90\]. The $j_{\text{corr}}$ increased with decreasing oxide thickness in 0.6 M NaCl (Fig. \[17\](a) and Fig. \[19\](a)). The trend reported here agrees with the literature \[25\] where the (0001) surface exhibited more corrosion susceptibility at the OCP while the (10T0), and (1120) surfaces are typically passive at open circuit and pit at potentials anodic to their OCPs \[25\]. In other studies, corrosion occurred more readily on planes near the basal orientation \[23\]. This inverse proportionality can be explained if oxidation “flux rate” of Mg$^{2+}$ is dependent on oxide film thickness. Suppose that oxidation was controlled by a Wagner type law. Corrosion rate due to flow of Mg$^{2+}$ and O$^{-2}$ or electrons and holes are both inversely proportional to oxide thickness \[91\]. More specifically, a more rapid passivation rate on the prismatic and pyramidal orientations may in turn lead to overall lower aqueous corrosion rates on these surfaces (Fig. \[17\]). Thicker hydroxides may also limit water penetration and cation transport. The thinnest oxide as well as the highest anodic charge produced over the 24 h period was observed on the basal plane (Fig. \[17\]). This suggests substantial direct cation ejection must occur as the anodic charge is much greater than that required for the film thicknesses noted. Consequently, the total anodic charge density produced (Fig. \[15\]) would not necessarily mean better passivation because the anodic charge density produced does not contribute to oxide formation. This agrees with the work shown here where the film covered basal plane had the highest anodic charge density (Fig. \[15\]) over 24 h in 0.6 M NaCl. However, the oxide on this film did not lead to better passivation in this aggressive environment.

4.3. The Effect of Surface Energy on Corrosion Thermodynamics

The effect of surface energy on corrosion is a factor in the corrosion of bare or almost bare Mg, such as in TRIS or EDTA. Referring to Fig. \[17\](b and c) and Fig. \[19\](b and c), it can be seen that $j_{\text{corr}}$ roughly follows surface energy trends (for immersion times less than 3 hours) estimated for Mg from embedded atom method and empirical electron theory \[28,92\]. These calculation techniques show that, in vacuum, the surface energy ($\gamma$) varies from 0.9 to 1.4 J/m$^2$ (Fig. \[19\](c)) and even as high as 1.65 J/m$^2$ \[28,92\]. Of course this is in vacuum and the actual value of $\gamma$ in TRIS and EDTA is unknown. The standard free energy of the following reaction applies to the case of Mg corroding in an acid where, in such a half-cell reaction, the number of nearest neighbors is not considered:

\[
\text{Mg} \rightarrow \text{Mg}^{2+} + 2e^- \left( E^{0,Mg} \right) \tag{12}
\]

\[
2H^+ + 2e^- \rightarrow H_2 \left( E^{0,SHE} \right) \tag{13}
\]

Or the overall reaction is:

\[
\text{Mg} + 2H^+ \rightarrow \text{Mg}^{2+} + H_2 \tag{14}
\]

This reaction will occur spontaneously in water. Consider the free energy of the reaction in Eq. \[14\] under standard conditions at room temperature, where Mgcorrodes in acidified water at unity activity of the dissolved species.

\[
\Delta G^0 = -nF\Delta E^0 = nF \left( E^{0,SHE} - E^{0,Mg} \right) \tag{15}
\]

In the case where $E^{0,SHE} = 0$ V and $E^{0,Mg} = -2.36$ V. Therefore, $\Delta G^0 = -456 \text{kJ} \text{mol}^{-1}$ for $n = 2$ and $F = 96485 \text{C}$$\text{mol}^{-1}$. The free energy of the overall reaction is quite negative. However, this energy is lowered by irrational planes which contain kinks, ledges and terraces containing many atoms with fewer bonds than the (0001) plane. This energy may be estimated from the surface energy difference per atom assuming a close packed surface converted to
energy per mole:

$$k \Delta \gamma = \left( \frac{1.4 J}{m^2} \right) \left( \frac{0.9 J}{m^2} \right) \left( \frac{m^2}{1 \times 10^{12} \text{ atoms}} \right) \left( \frac{6.023 \times 10^{23} \text{ atoms}}{\text{mol}} \right)$$

$$= 30.1 \text{ kJ/mol} \quad (16)$$

for the case of high energy surface sites with $1.4 \text{ J/m}^2$ as determined from $\beta_{[0001]} \sim 60^\circ$ along $\alpha = 0^\circ$ compared to $0.9 \text{ J/m}^2$ for the close packed $[0001]$ plane [28,52]. Here $\gamma$ is the surface energy term as shown in Fig. 19(c) and $k$ is a correction factor. The free energy change for the overall reaction given by Eq. (14) is more favorable by $30.1 \text{ kJ/mol}$. This is equivalent to a lowered standard half-cell potential, $E_{\text{Mg}}^0_{\text{Mg}_{\text{hkl}}}$, now written to describe a specific [hkl] plane:

$$E_{\text{Mg}}^0_{\text{Mg}_{\text{hkl}}} = \frac{\sum n \Delta \gamma_{\text{ox}} - \sum n \Delta \gamma_{\text{red}} - \sum n \Delta \gamma_{\text{hkl}}}{nF} \quad (17)$$

When $n=2$ and $\nu$ is the stoichiometric coefficient. Under these conditions, the standard half-cell potential, $E_{\text{Mg}}^0_{\text{Mg}_{\text{hkl}}}$, would be lowered from $-2.36 \text{ V}$ to $-2.52 \text{ V}$ for $\beta_{[0001]} = 60^\circ$ along $\alpha = 0^\circ$ compared to a $[0001]$ plane and the additional thermodynamic driving force is $160 \text{ mV}$. However, this indicates that the reaction occurs more readily from a thermodynamic view. This driving force is not great (\sim 7\% change) for Mg because the oxidation reaction already occurs at OCP (such as $-1.74 \text{ V}_{\text{SCE}}$) far from equilibrium. Thus, the effect of surface energy is rationalized to produce some effect on bare electrodes but it is easily overcome by other factors, such as the role of the oxide which regulates $j_{\text{corr}}$ as discussed above. It is recognized that kinetics effects such as lowering the activation barrier for Mg oxidation are not accounted for.

### 4.4. Corrosion Rates on Mg Bare surfaces

The effect of crystallographic orientation on OCP corrosion rate was observed in exposure environments where the MgO film is dissolved and little of the Mg(OH)$_2$ film was precipitated as depicted in Fig. 18. The variation in $j_{\text{corr}}$ with crystallographic orientation was different than that in the unbuffered, chloride environments (Figs. 15, 17 and 19) with a slight increase in $j_{\text{corr}}$ at $\beta_{[0001]} \sim 35-60^\circ$. This trend correlates with the vacuum surface energy (Fig. 19(b and c)). TRIS and EDTA removed most of the oxide film. This would lead to the correlation between $j_{\text{corr}}$ and surface energy (Fig. 19(b and c)) with a slight increase in $j_{\text{corr}}$ at $\beta_{[0001]}$ from 35 to 60° (Fig. 17). It can be speculated that by removing the effects of the oxide film, $j_{\text{corr}}$ might correlate better with surface energy. However, $j_{\text{corr}}$ exhibited a correlation with high surface energy only at short exposure times (Fig. 19(b)). This correlation during the initial stages of immersion is particularly seen in Fig. 17(b and c) after 0 hours in EDTA and TRIS where there is little oxide formed. However, after longer immersion times, the surface energy trends with orientation are no longer dominant, potentially because the rapid $j_{\text{corr}}$ of Mg resulted in local saturation of the buffer solution which triggered local oxide formation.

### 5. CONCLUSIONS

1. A method was reported to acquire EIS derived $j_{\text{corr}}$ data from isolated individual grain facets with specific crystallographic orientations identified by the EBSD method. Anodic charge and corrosion rate were both accurately calculated from $R_p$ determinations during open circuit corrosion of Mg for a large number of specified crystallographic orientations. Corrosion properties of Mg were highly dependent on both the crystal
orientations of the exposes grain facets, the corrosive environment, and time.

2. Open circuit corrosion, as a function of crystallographic orientation, exhibited a trend towards a faster corrosion rate and greater anodic charge at orientations near the (0001) plane relative to others for commercially pure magnesium exposed in unbuffered, sodium chloride and also after long exposures in buffered chelating environments.

3. In contrast, open circuit corrosion, as a function of crystallographic orientation, exhibited a trend towards a faster corrosion rate and greater anodic charge at orientations associated with crystal surfaces with high surface energies. These high index planes were found at intermediate ζ angles within the stereographic triangle in buffered, chelating environments. However, this trend was only observed for short term exposures.

4. Film formation is highly dependent on the exposure environment and time. A thick precipitated Mg(OH)$_2$ film with an inner MgO layer was readily formed in alkaline, chloride environments in unbuffered solutions in short time periods. Meanwhile, this film did not form as readily in the near neutral pH, non-chloride TRIS and EDTA solutions, leading to a crystallographic orientation dependence that correlated with the surface energy of high index planes at short exposure times.

5. Oxide thickness was strongly dependent on crystallographic orientation in the chloride containing environment, 0.6 M NaCl. The thickest oxide was observed on the (10T0), and (1120) planes while the thinnest oxide was found on the (0001) plane after several hours which was preserved at longer times. The corrosion rate was inversely proportional to oxide thickness and the subsequent crystal orientation dependency of corrosion correlated with orientation effects on oxide thickness.

6. In the non-chloride TRIS and EDTA environments, a slight increase in the corrosion charge was seen at β = 60° and a correlation between high corrosion rate and high surface energies associated with high index planes was seen. The crystallographic orientation dependence on the corrosion rate was related to the effect of surface energy on the $1/2$ cell potential for Mg oxidation to Mg$^{2+}$, even though open circuit corrosion of Mg occurs at open circuit potentials far from this equilibrium potential. However, the surface energy correlation was observed to be overtaken with time by the strong oxide film orientation dependency consistent with Mg(OH)$_2$ film detection by Raman Spectroscopy.

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